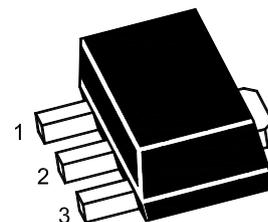


Features

- Sensitive gate silicon controlled rectifiers
- Reverse blocking thyristors

SOT-89



1.Cathode(K) 2.Anode(A)3.Gate(G)

Equivalent Circuit



Marking Code :

MCR100-4SQ : MCR100-4

MCR100-6SQ : MCR100-6

MCR100-8SQ : MCR100-8

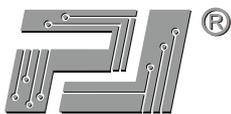
Absolute Maximum Ratings

Ratings at 25°C ambient temperature unless otherwise specified.

Parameter	Symbol	Value	Unit
Peak Repetitive Off-State Voltage ^{Note1} ($T_J = -40^{\circ}\text{C} \sim 110^{\circ}\text{C}$, Sine Wave, 50 to 60 Hz, Gate Open)	$V_{\text{DRM}}, V_{\text{RRM}}$	200 400 600	V
On-State RMS Current	$I_{\text{T(RMS)}}$	0.8	A
Peak Non-Repetitive Surge Current (1/2 Cycle, Sine Wave, 60 Hz, $T_J = 25^{\circ}\text{C}$)	I_{TSM}	8	A
Circuit Fusing Considerations ($t = 8.3\text{ms}$)	I^2t	0.415	A^2s
Forward Peak Gate Power (Pulse Width $\leq 1 \mu\text{s}$)	P_{GM}	0.1	W
Forward Average Gate Power ($t = 8.3\text{ms}$)	$P_{\text{G(AV)}}$	0.1	W
Peak Gate Current – Forward (Pulse Width $\leq 1 \mu\text{s}$)	I_{GM}	1	A
Peak Gate Voltage – Reverse (Pulse Width $\leq 1 \mu\text{s}$)	V_{GRM}	5	V
Operating Junction Temperature Range	T_J	-40 to +110	$^{\circ}\text{C}$
Storage Temperature Range	T_{STG}	-40 to +150	$^{\circ}\text{C}$

Note:

1. V_{DRM} and V_{RRM} for all types can be applied on continuous basis. Ratings apply for zero negative gate voltage; however, positive gate voltage shall not be applied concurrent with negative potential on the anode. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.



Electrical Characteristics (T_A=25°C)

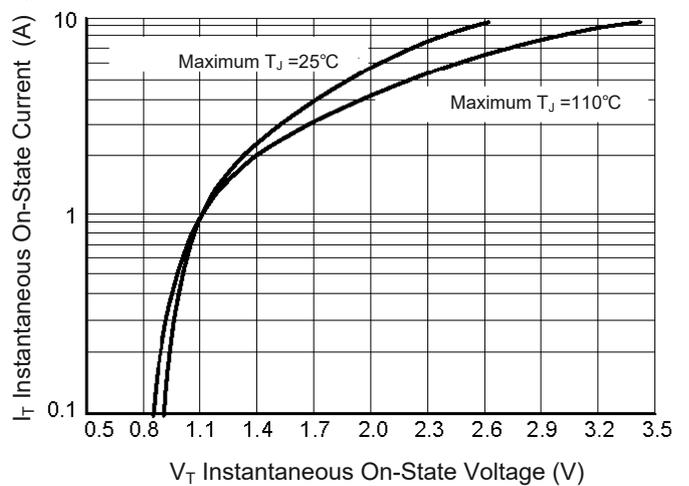
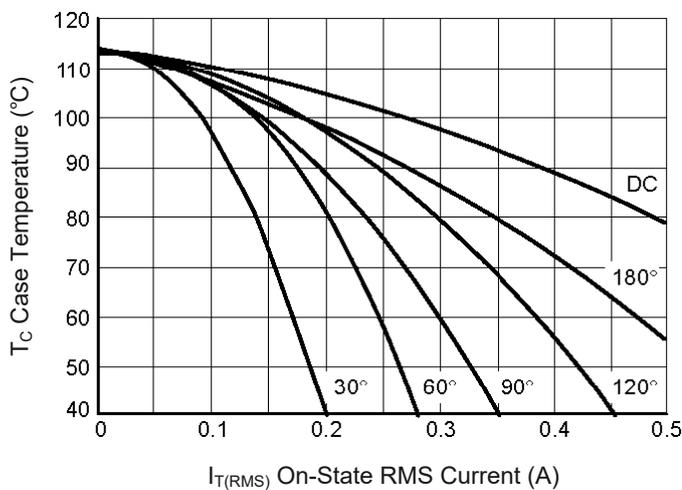
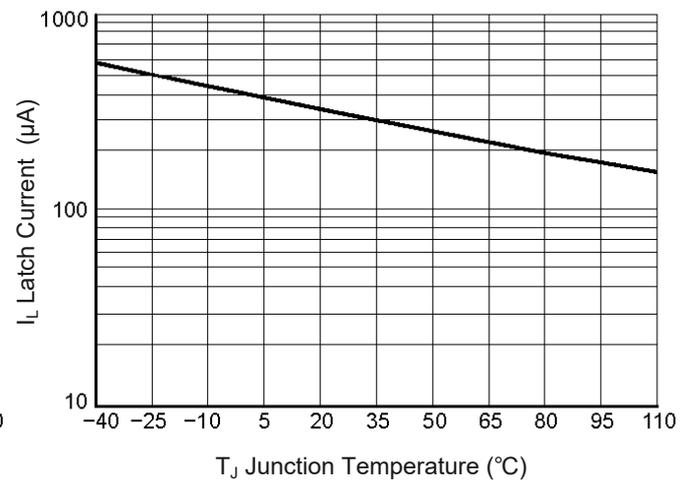
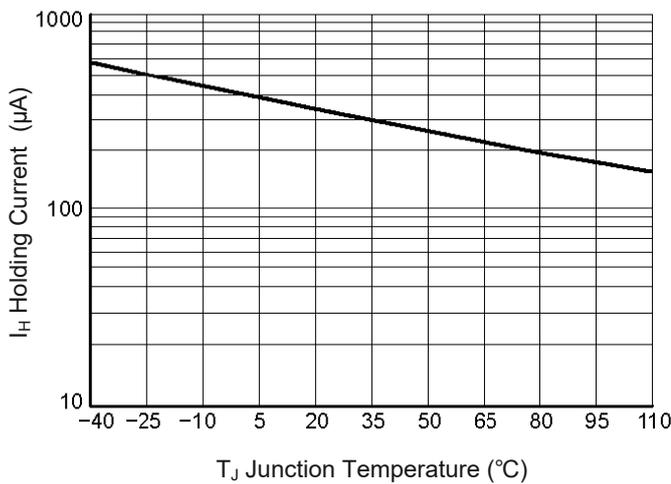
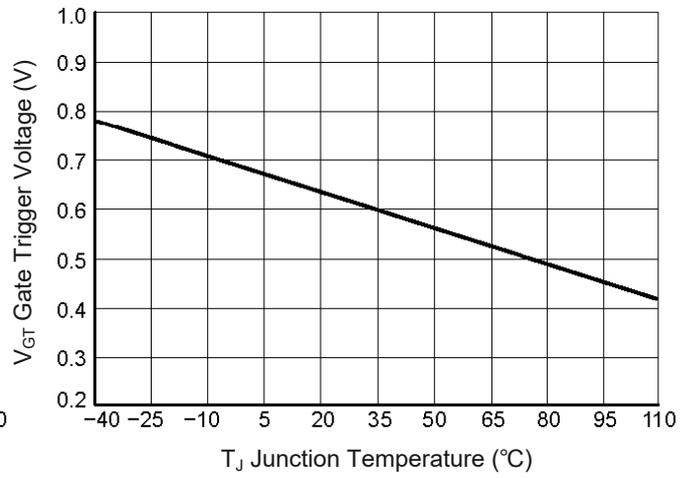
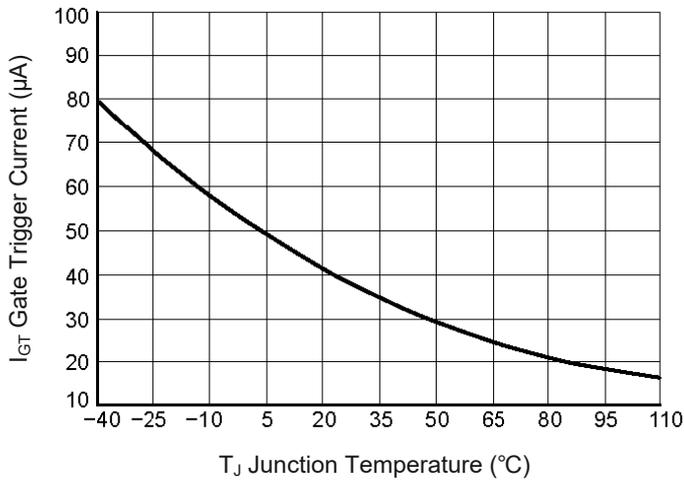
Parameter	Symbol	Value	Unit
Peak Forward or Reverse Blocking Current ^{Note2} at V _D = Rated V _{DRM} and V _{RRM} , R _{GK} =1KΩ	I _{DRM} , I _{RRM}	10	μA
Peak Forward On-State Voltage ^{Note1} at I _{TM} = 0.8 A	V _{TM}	1.7	V
Gate Trigger Current ^{Note3} at V _{AK} = 7 V, R _L = 100 Ω	I _{GT}	200	μA
Holding Current ^{Note2} at V _{AK} = 7 V, Initiating Current = 20 mA	I _H	T _C = 25°C 5	mA
		T _C = -40°C 10	
Latch Current at V _{AK} = 7 V, I _g = 1 mA	I _L	T _C = 25°C 10	mA
		T _C = -40°C 15	
Gate Trigger Voltage ^{Note3} at V _{AK} = 7 V, R _L = 100 Ω	V _{GT}	T _C = 25°C 0.8	V
		T _C = -40°C 1.2	

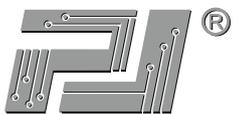
Note:

- 1.Indicates pulse test width ≤ 1 ms, duty cycle ≤1%
- 2.R_{GK} = 1 KΩ included in measurement
- 3.Does not include R_{GK} in measurement



Typical Characteristic Curves

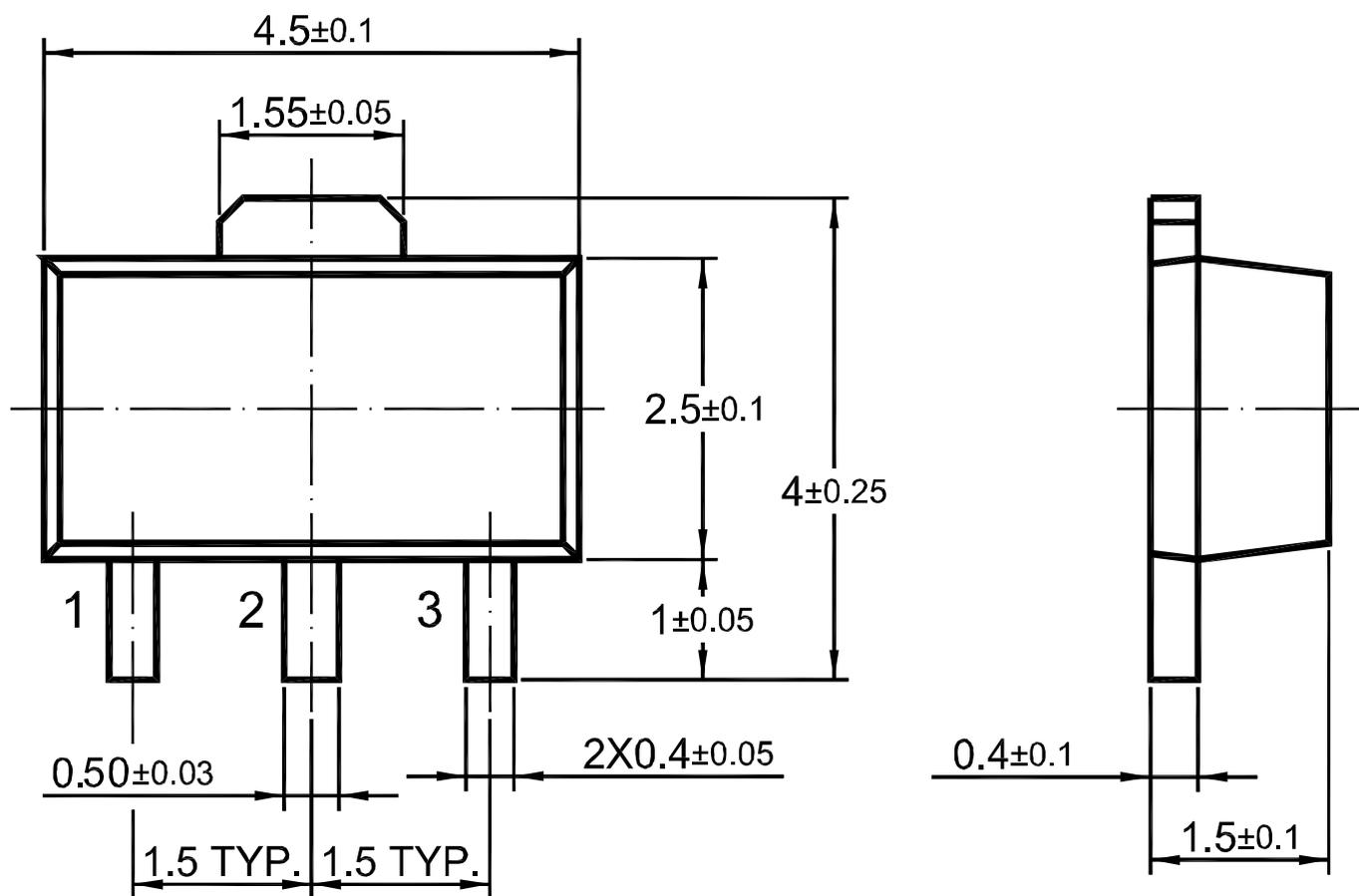




Package Outline

SOT-89

Dimensions in mm

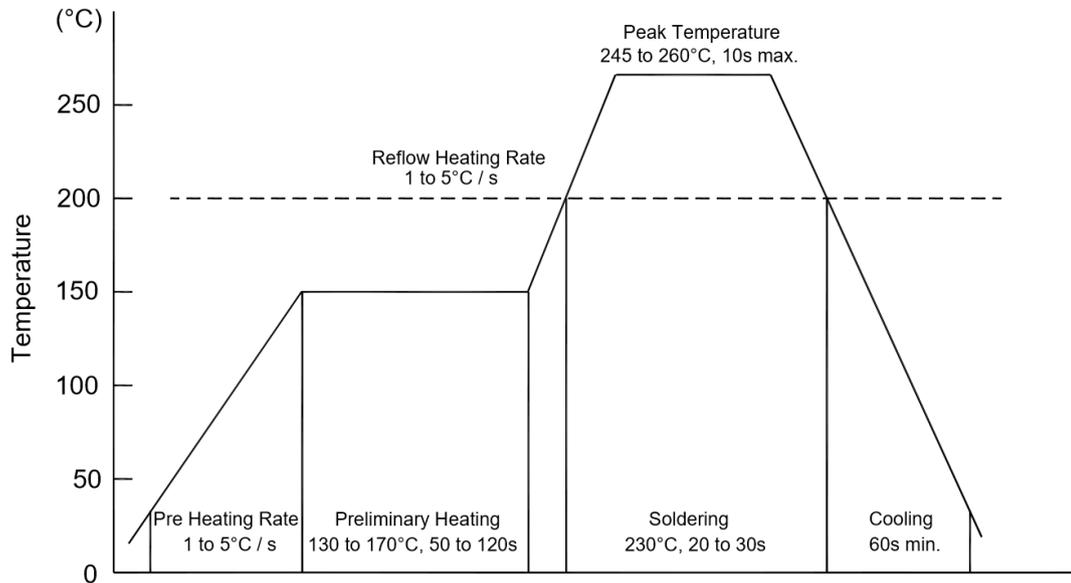


Ordering Information

Device	Package	Shipping
MCR100 Series	SOT-89	3,000PCS/Reel&13inches

Conditions of Soldering and Storage

◆ Recommended condition of reflow soldering



Recommended peak temperature is over 245 °C. If peak temperature is below 245 °C, you may adjust the following parameters:

- Time length of peak temperature (longer)
- Time length of soldering (longer)
- Thickness of solder paste (thicker)

◆ Conditions of hand soldering

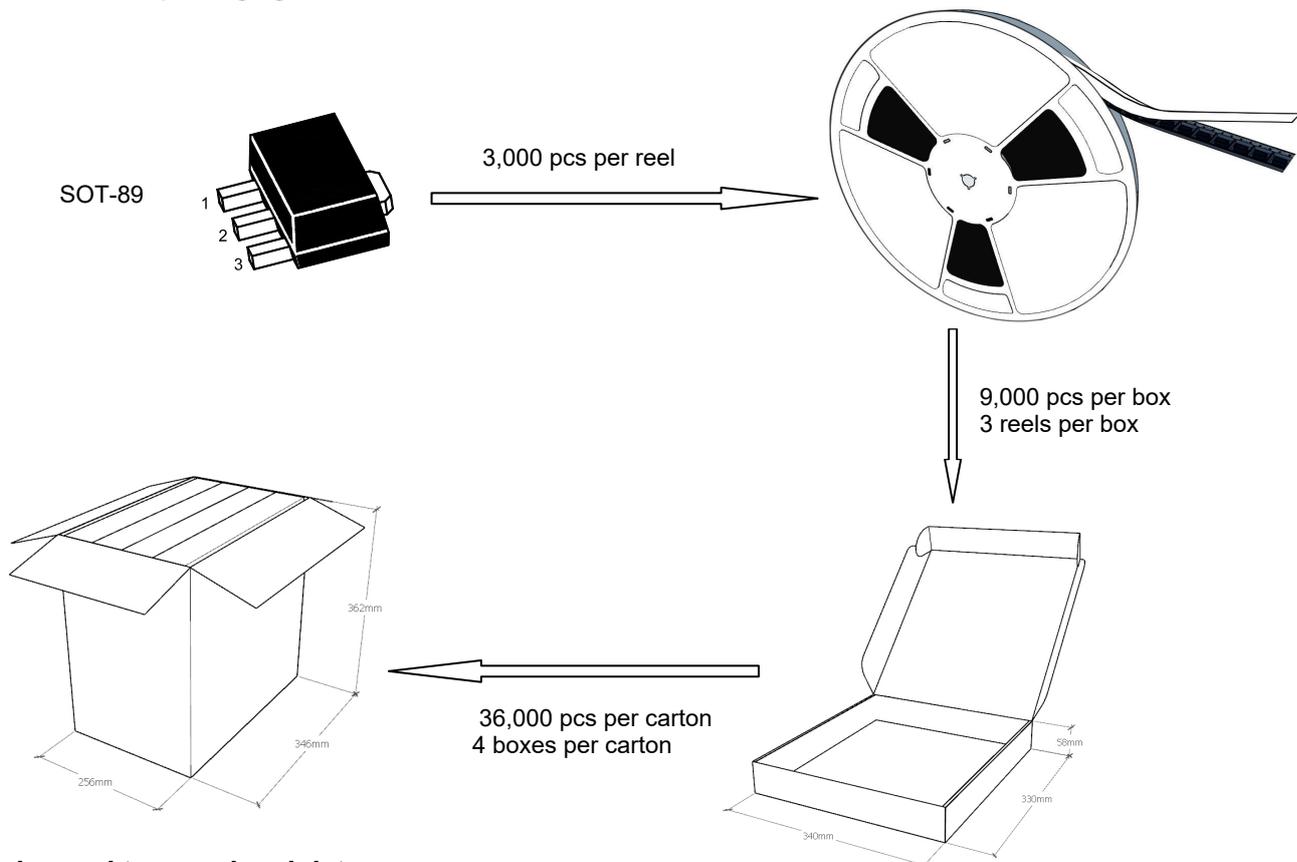
- Temperature: 370 °C
- Time: 3s max.
- Times: one time

◆ Storage conditions

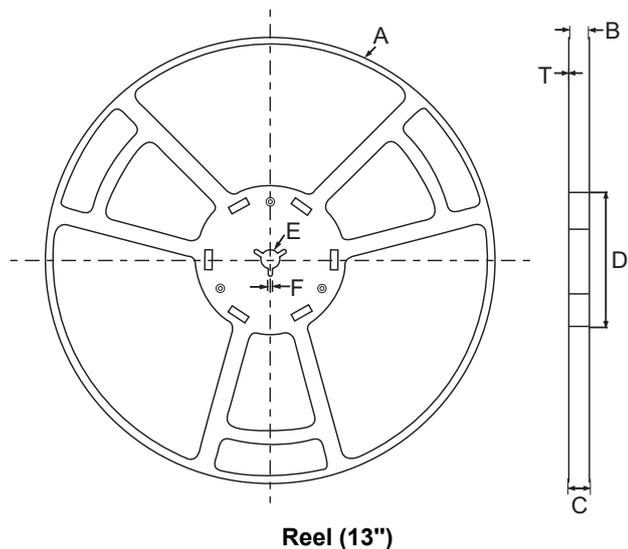
- **Temperature**
5 to 40 °C
- **Humidity**
30 to 80% RH
- **Recommended period**
One year after manufacturing

Package Specifications

- The method of packaging



◆ Embossed tape and reel data



symbol	Value(unit:mm)
A	$\phi 330\pm 1$
B	12.7 ± 0.5
C	16.5 ± 0.3
D	$\phi 99.5\pm 0.5$
E	$\phi 13.6\pm 0.3$
F	2.8 ± 0.3
T	1.9 ± 0.2

